

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L5	5827	vertical near5 (fet mosfet (field near effect near transistor))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/11 14:23
L6	53340	(block\$3 drift\$3) near (layer film region area)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/11 14:23
L7	873	L5 and L6	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/11 14:23